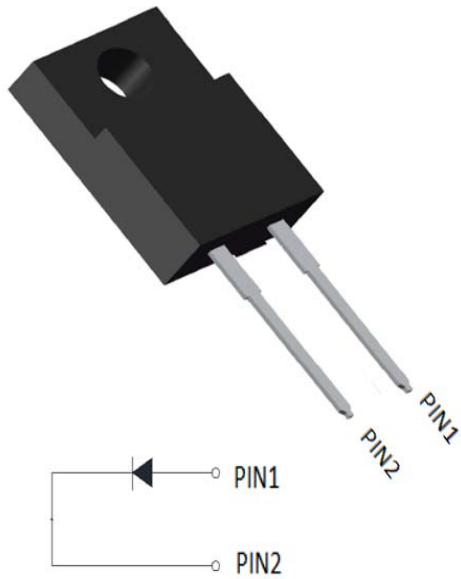


Ultra-Fast Recovery Diodes 12A FRED Pt



Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** ITO-220AC
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MUR1260FL
Device marking code			MUR1260FL
Repetitive Peak Reverse Voltage	VRRM	V	600
Average Rectified Output Current @60Hz sine wave, R-load, T _c (FIG.1)	I _O	A	12
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _j =25°C	I _{FSM}	A	120
Current Squared Time @1ms≤t≤8.3ms T _j =25°C,	I ² t	A ² s	93
Storage Temperature	T _{stg}	°C	-55 ~ +175
Junction Temperature	T _j	°C	-55 ~ +175
Typical Junction capacitance @4V,1MHz	C _j	pF	92
Mounting torque @recommend torque: 5kg·cm	Tor	kg·cm	8



MUR1260FL

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max	
Instantaneous forward voltage drop per diode	V_{FM}	V	IFM=12.0A @Tj=25°C	-	2.4	3.0	
			IFM=12.0A @Tj=150°C	-	2.0	2.4	
DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	uA	VRM=VRRM Tj=25°C	-	-	10	
	I_{RRM2}		VRM=VRRM Tj=150°C	-	30	200	
Reverse Recovery Time	T_{rr}	ns	IF=0.5A IRM=1A IRR=0.25A Tj=25°C	-	20	25	
			Tj=25°C		34.5		
			Tj=125°C		66.5		
Peak recovery current	I_{RRM}	A	IF=12A di/dt=-200A/us VRM=200V	Tj=25°C	-	2.45	-
				Tj=125°C	-	5.55	-
Reverse recovery charge	Q_{rr}	nC		Tj=25°C	-	42.5	-
				Tj=125°C	-	186.5	-

■Thermal Characteristics (Tj=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MUR1260FL
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	°CW	4.0
Thermal Resistance	Between junction and Air	$R_{\theta J-A}$	°CW	50

■Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MUR1260FL	Approximate 1.6	50	1000	5000	Tube



MUR1260FL

■ Characteristics (Typical)

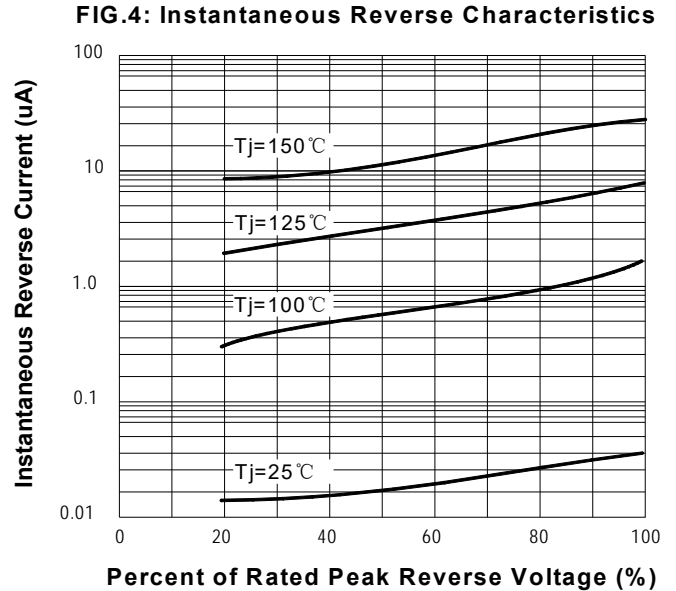
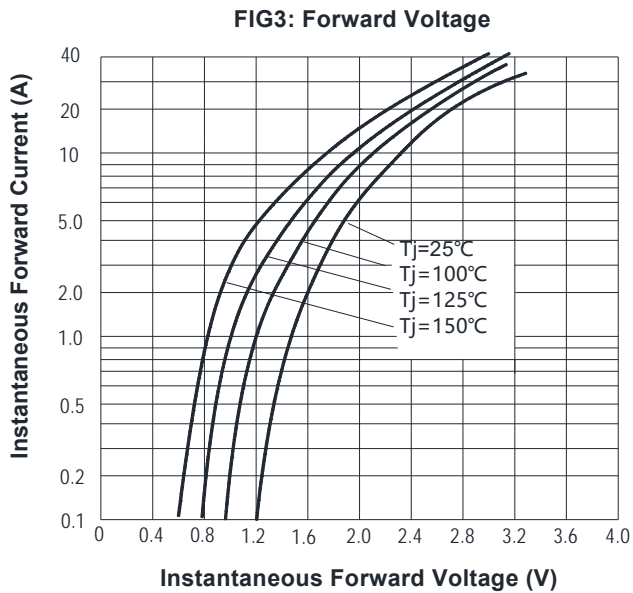
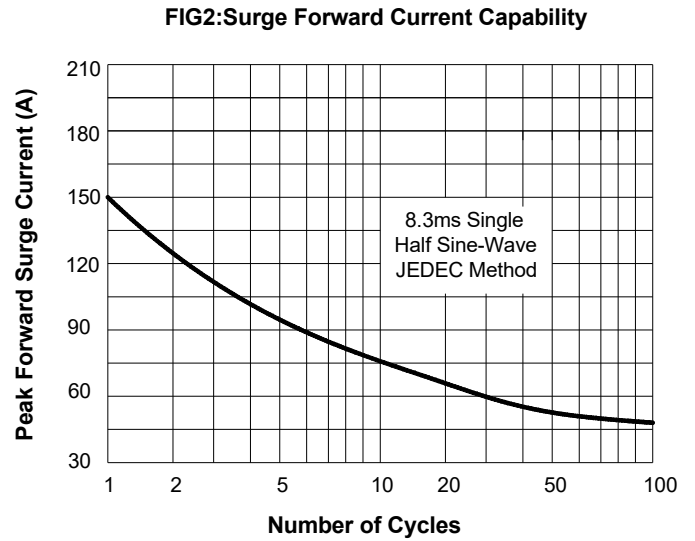
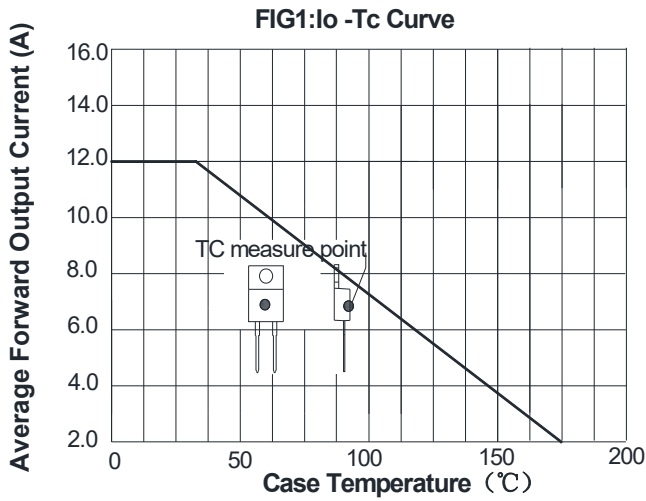
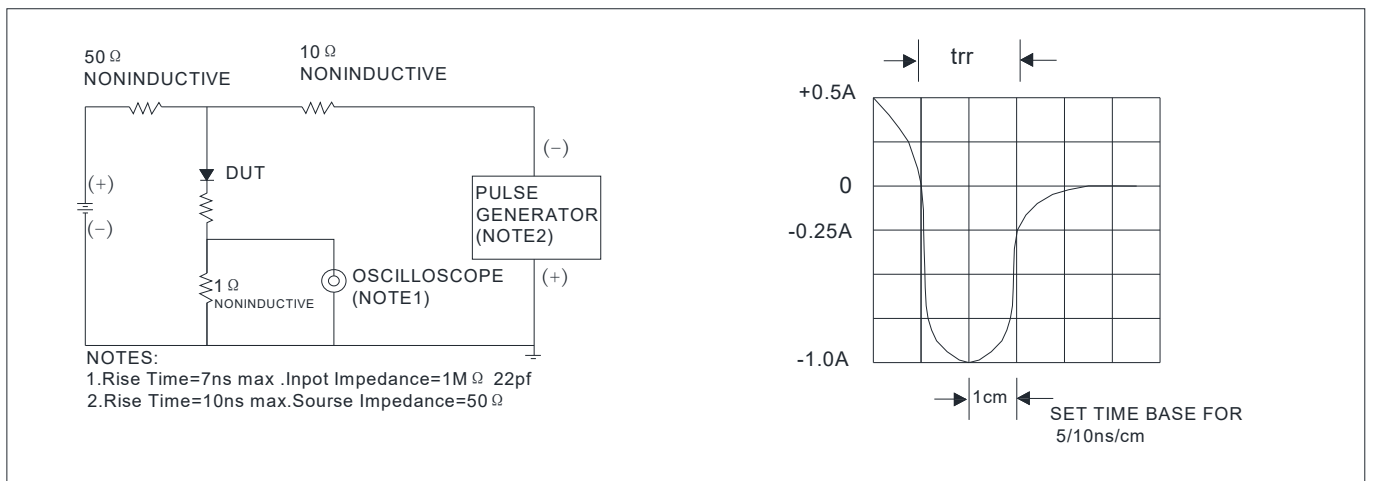


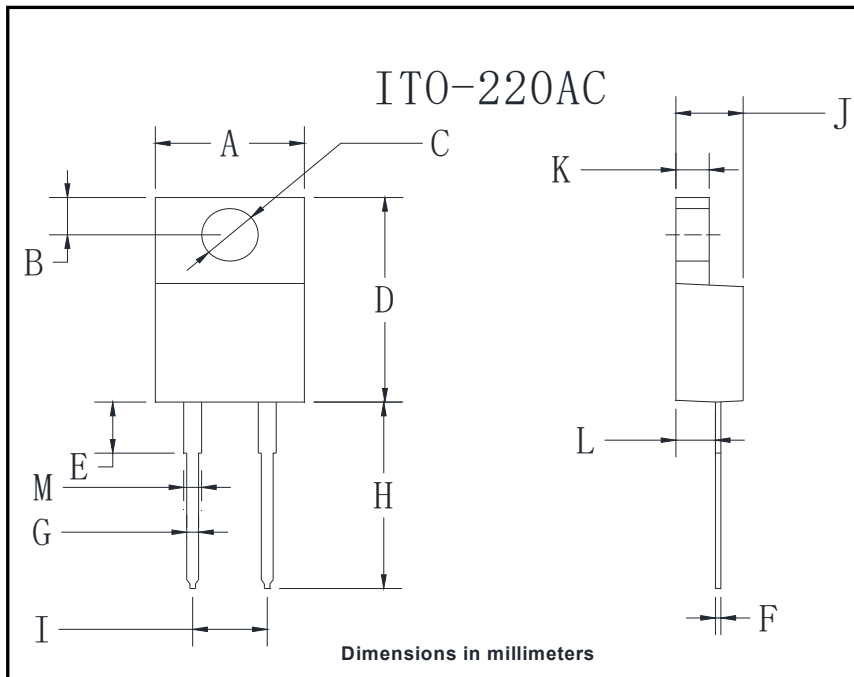
FIG.5: Diagram of circuit and Testing wave form of reverse recovery time





MUR1260FL

■Outline Dimensions



ITO-220AC		
Dim	Min	Max
A	9.7	10.7
B	2.15	3.25
C	2.6	3.8
D	14.4	15.9
E	3.1	4.5
F	0.4	0.8
G	0.4	0.9
H	12.7	14.2
I	3.6	5.9
J	3.9	5.1
K	2.1	3.56
L	2.1	3.2
M	1.0	1.8



MUR1260FL

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